GENERAL DESCRIPTION

Glass passivated, sensitive gate thyristors in a plastic envelope, intended for use in general purpose switching and applications. phase control

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V _{DRM} , V _{RRM} I _{T(AV)} I _{T(RMS)} I _{TSM}	BTA151- Repetitive peak off-state voltages Average on-state current RMS on-state current Non-repetitive peak on-state current	500R 500 7.5 12 100	650R 650 7.5 12 100	800R 800 7.5 12 100	V A A A

SYMBOL

PINNING - SOT82

PIN	DESCRIPTION
1	cathode
2	anode
3	gate
tab	anode

PIN CONFIGURATION

k а g

LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V _{drm} , V _{rrm}	Repetitive peak off-state voltages		-	-500R 500 ¹	-650R 650 ¹	-800R 800	V
I _{T(AV)} I _{T(RMS)} I _{TSM}	Average on-state current RMS on-state current Non-repetitive peak on-state current	half sine wave; $T_{mb} \le 109$ °C all conduction angles half sine wave; $T_j = 25$ °C prior to surge	-		7.5 12		A A
		t = 10 ms t = 8.3 ms	-		100 110		A A
l ² t	I ² t for fusing	t = 10 ms	-		50		A ² s
dl _⊤ /dt	Repetitive rate of rise of on-state current after triggering	$\begin{split} I_{TM} &= 20 \text{ A}; I_{G} = 50 \text{ mA}; \\ dI_{G}/dt &= 50 \text{ mA}/\mu\text{s} \end{split}$	-		50		A/μs
I _{GM}	Peak gate current		-		2		A
I _{GM} V _{GM}	Peak gate voltage		-		5		V
V _{RGM}	Peak reverse gate voltage		-		12		V
I P _{GM}	Peak gate power		-		5		W
$\begin{array}{c} P_{G(AV)} \\ T_{stg} \\ T_{j} \end{array}$	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	-40 -		0.5 150 125		ວໍລິ

1 Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.

BTA151 series

BTA151 series

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance		-	-	1.3	K/W
R _{th j-a}	junction to mounting base Thermal resistance junction to ambient	in free air	-	60	-	K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

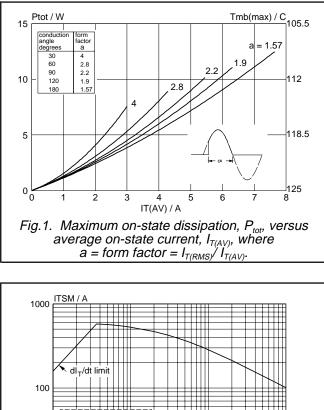
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	2	4	mA
	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	10	40	mA
	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	7	16	mA
V _τ	On-state voltage	$I_{T} = 23 \text{ A}$	-	1.4	1.75	V
V _{GT}	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	0.6	1.5	V
0.		$V_{D} = V_{DRM(max)}$; $I_{T} = 0.1 \text{ A}$; $T_{j} = 125 \text{ °C}$	0.25	0.4	-	V
I _D , I _R	Off-state leakage current	$V_D = V_{DRM(max)}^{ORM(max)}; V_R = V_{RRM(max)}; T_j = 125 \text{°C}$	-	0.1	0.5	mA

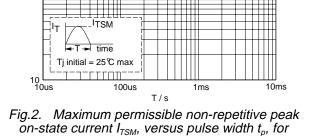
DYNAMIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

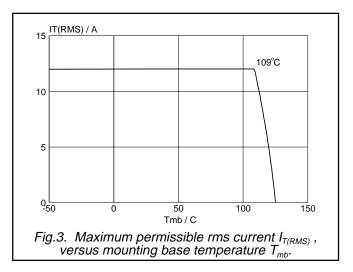
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	$V_{D} = 67\% V_{DRM(max)}; T_{j} = 125 °C;$ exponential waveform Gate open circuit $R_{GK} = 100 \Omega$	50 200	130 1000	-	V/μs V/μs
t _{gt}	Gate controlled turn-on time	$I_{TM} = 40 \text{ A}; V_D = V_{DRM}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	μs
t _q	Circuit commutated turn-off time		-	70	-	μs

BTA151 series





on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \le 10$ ms.



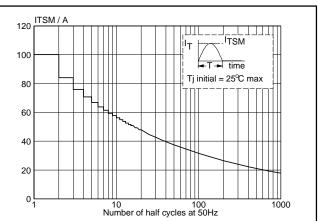


Fig.4. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus number of cycles, for sinusoidal currents, f = 50 Hz.

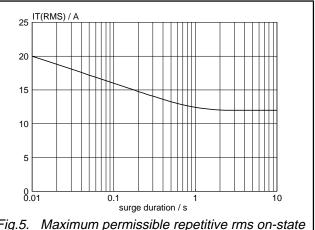
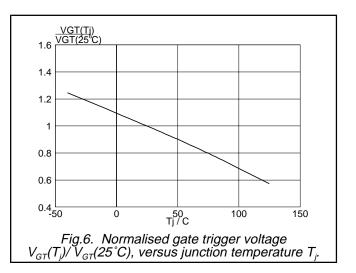
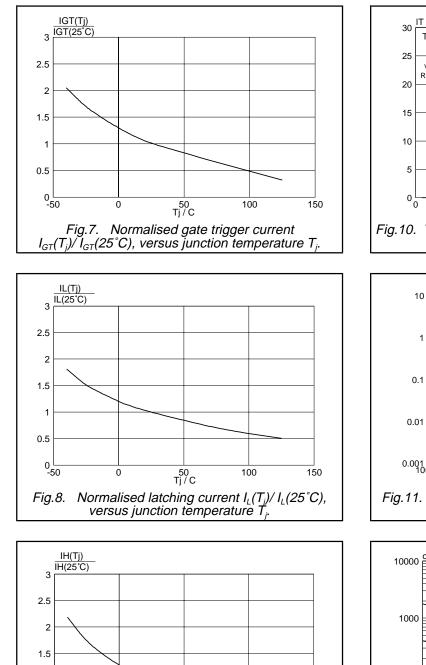


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 109$ °C.



BTA151 series



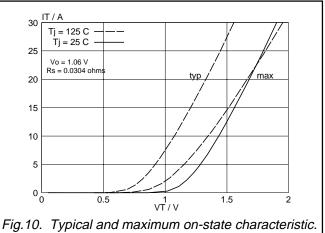
50 Tj / C

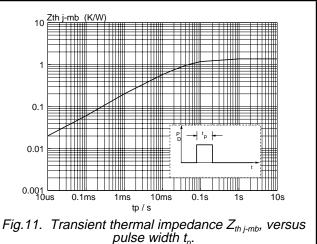
Fig.9. Normalised holding current $I_H(T_j)/I_H(25^{\circ}C)$, versus junction temperature T_j .

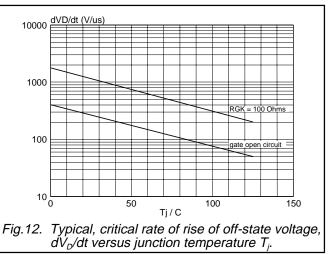
100

150

0







1

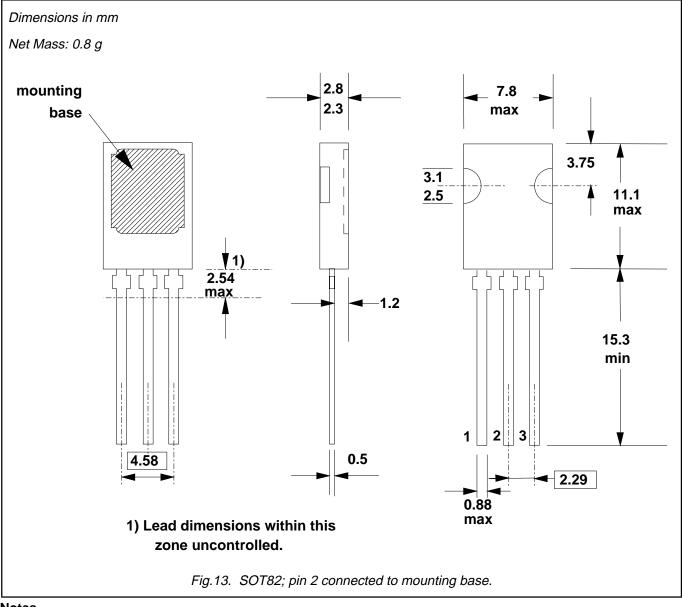
0.5

0 └ -50

Product specification

BTA151 series

MECHANICAL DATA



Notes

Refer to mounting instructions for SOT82 envelopes.
Epoxy meets UL94 V0 at 1/8".

DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.					
Application information					
Where application information is given, it is advisory and does not form part of the specification.					

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